



SamHop Microelectronics Corp.

STU/D2455PLS

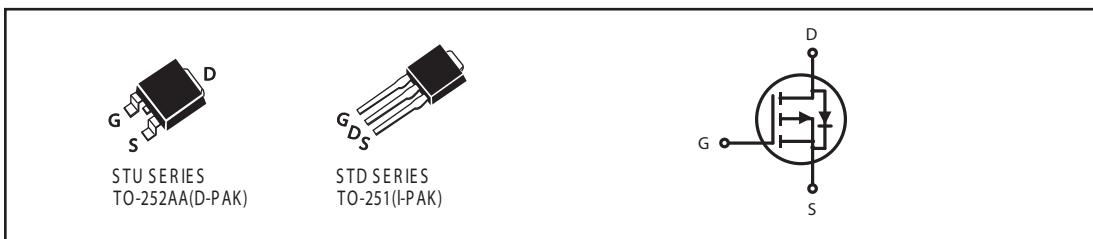
Dec 30, 2005

P-Channel Enhancement Mode Field Effect Transistor

| PRODUCT SUMMARY | | |
|------------------|----------------|------------------------------|
| V _{DSS} | I _D | R _{DSON} (mΩ) Max |
| -55V | -24 | 42 @ V _{GS} = -10V |
| | | 55 @ V _{GS} = -4.5V |

FEATURES

- Super high dense cell design for low R_{DSON}.
- Rugged and reliable.
- TO-252 and TO-251 Package.

ABSOLUTE MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|---|-----------------------------------|------------|------|
| Drain-Source Voltage Rating | V _{spike} ^c | -60 | V |
| Drain-Source Voltage | V _{DS} | -55 | V |
| Gate-Source Voltage | V _{GS} | ±20 | V |
| Drain Current-Continuous @ T _c =25°C -Pulsed ^a | I _D | -24 | A |
| | I _{DM} | -72 | A |
| Drain-Source Diode Forward Current | I _S | -20 | A |
| Maximum Power Dissipation @ T _c =25°C | P _D | 50 | W |
| Operating Junction and Storage Temperature Range | T _J , T _{STG} | -55 to 175 | °C |

THERMAL CHARACTERISTICS

| | | | |
|---|------------------|----|------|
| Thermal Resistance, Junction-to-Case | R _{θJC} | 3 | °C/W |
| Thermal Resistance, Junction-to-Ambient | R _{θJA} | 50 | °C/W |

STU/D2455PLS

ELECTRICAL CHARACTERISTICS ($T_c=25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Condition | Min | Typ ^c | Max | Unit |
|---|--------------|---|-----|------------------|-----|---------|
| OFF CHARACTERISTICS | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS}=0V, I_D=-250\mu A$ | -55 | | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=-44V, V_{GS}=0V$ | | -1 | | μA |
| Gate-Body Leakage | I_{GSS} | $V_{GS}=\pm 20V, V_{DS}=0V$ | | ± 100 | | nA |
| ON CHARACTERISTICS ^a | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=-250\mu A$ | -1 | -1.7 | -3 | V |
| Drain-Source On-State Resistance | $R_{DS(ON)}$ | $V_{GS}=-10V, I_D=-10A$ | | 33 | 42 | m ohm |
| | | $V_{GS}=-4.5V, I_D=-6A$ | | 42 | 55 | m ohm |
| On-State Drain Current | $I_{D(ON)}$ | $V_{DS}=-10V, V_{GS}=-10V$ | -24 | | | A |
| Forward Transconductance | g_F | $V_{DS}=-10V, I_D=-10A$ | | 16 | | S |
| DYNAMIC CHARACTERISTICS ^b | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS}=-30V, V_{GS}=0V$ $f=1.0MHz$ | | 1730 | | pF |
| Output Capacitance | C_{oss} | | | 185 | | pF |
| Reverse Transfer Capacitance | C_{rss} | | | 125 | | pF |
| Gate resistance | R_g | $V_{GS}=0V, V_{DS}=0V, f=1.0MHz$ | | 1.7 | | ohm |
| SWITCHING CHARACTERISTICS ^b | | | | | | |
| Turn-On Delay Time | $t_{D(ON)}$ | $V_{DD}=-30V$ $I_D=-1A$ $V_{GS}=-10V$ $R_{GEN}=6\text{ ohm}$ | | 21 | | ns |
| Rise Time | t_r | | | 25 | | ns |
| Turn-Off Delay Time | $t_{D(OFF)}$ | | | 127 | | ns |
| Fall Time | t_f | | | 35 | | ns |
| Total Gate Charge (10V) | Q_g | $V_{DS}=-30V, I_D=-10A$ $V_{GS}=-10V$ | | 31 | | nC |
| Total Gate Charge (4.5V) | | | | 13.5 | | nC |
| Gate-Source Charge | Q_{gs} | | | 3.5 | | nC |
| Gate-Drain Charge | Q_{gd} | | | 7 | | nC |

STU/D2455PLS

ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|---|----------|---------------------------|-----|-------|------|------|
| DRAIN-SOURCE DIODE CHARACTERISTICS ^a | | | | | | |
| Diode Forward Voltage | V_{SD} | $V_{GS} = 0V, I_S = -10A$ | | -0.92 | -1.3 | V |

Notes

- a.Pulse Test:Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.
- b.Guaranteed by design, not subject to production testing.
- c.Guaranteed when external $R_g=6\ \Omega$ and $t_f < t_{f\ max}$

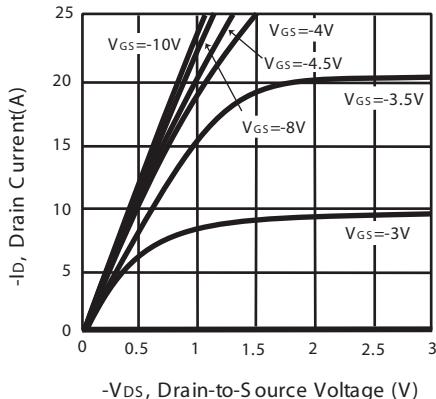


Figure 1. Output Characteristics

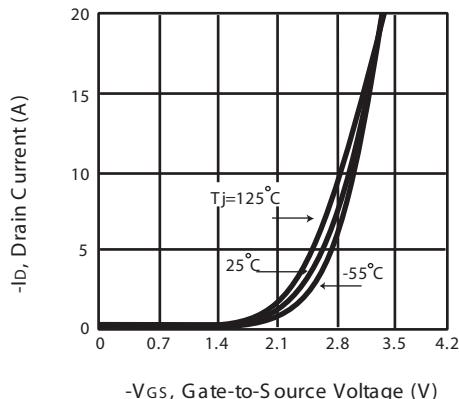


Figure 2. Transfer Characteristics

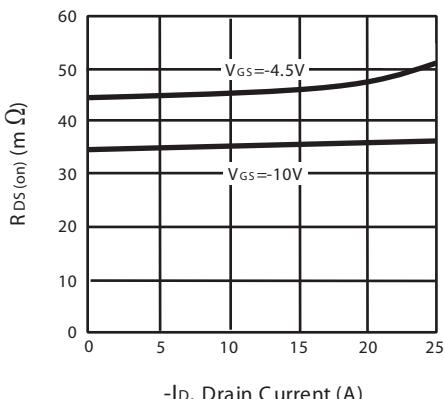


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

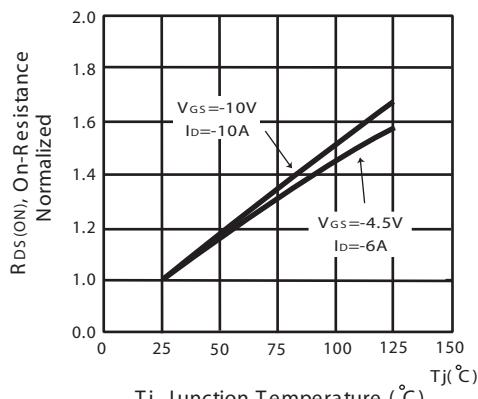


Figure 4. On-Resistance Variation with Drain Current and Temperature

STUD2455PLS

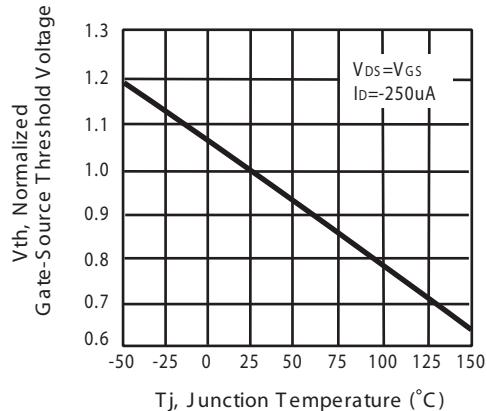


Figure 5. Gate Threshold Variation with Temperature

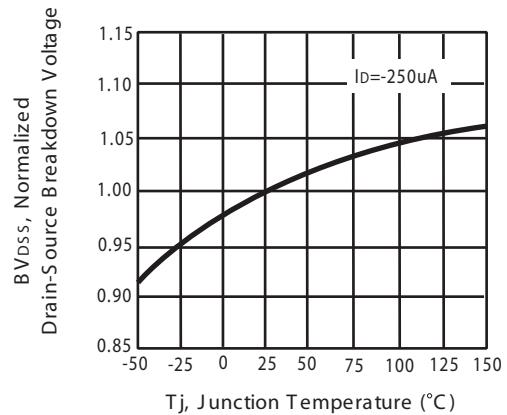


Figure 6. Breakdown Voltage Variation with Temperature

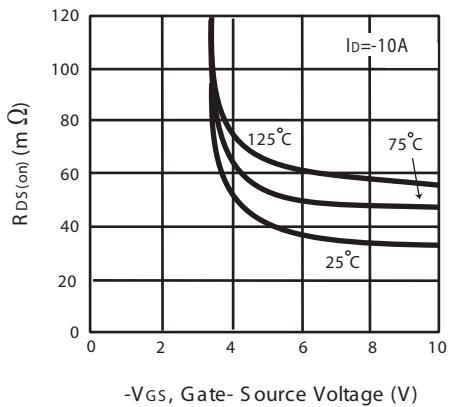


Figure 7. On-Resistance vs. Gate-Source Voltage

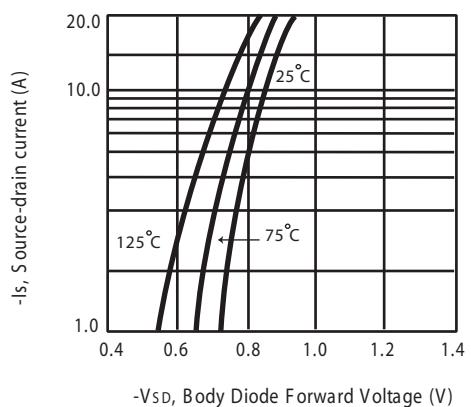
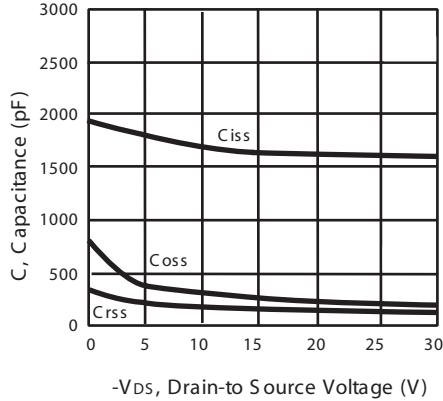


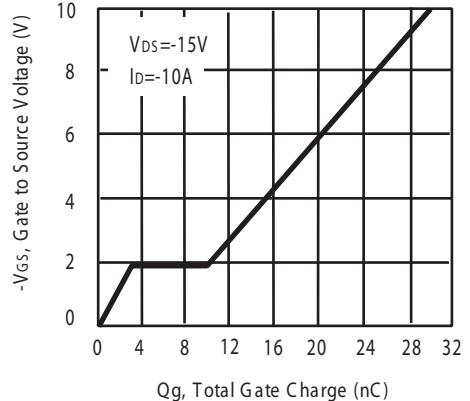
Figure 8. Body Diode Forward Voltage Variation with Source Current

STU/D2455PLS



-V_{DS}, Drain-to Source Voltage (V)

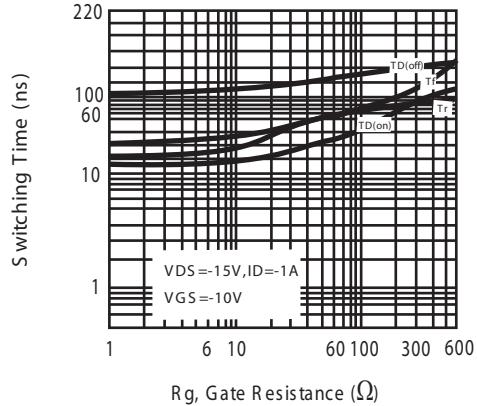
Figure 9. Capacitance



-V_{GS}, Gate to Source Voltage (V)

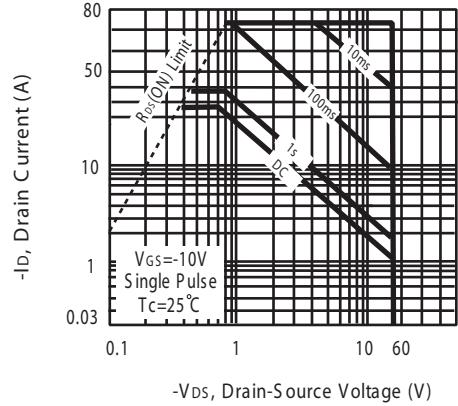
Q_g, Total Gate Charge (nC)

Figure 10. Gate Charge



R_g, Gate Resistance (Ω)

Figure 11. switching characteristics



-V_{DS}, Drain-Source Voltage (V)

Figure 10. Maximum Safe Operating Area

STU/D2455PLS

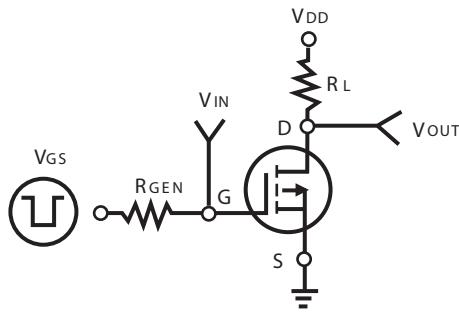


Figure 11. S switching Test Circuit

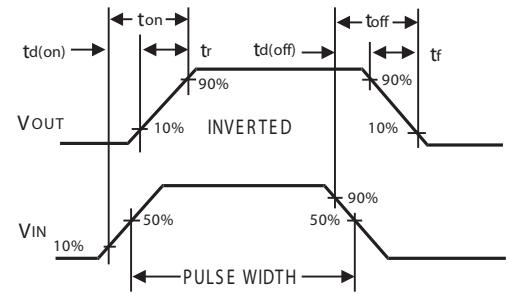


Figure 12. S switching Waveforms

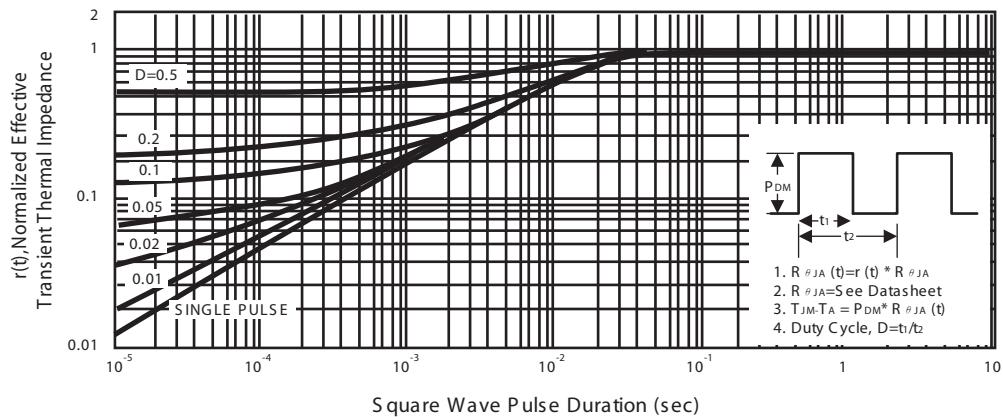
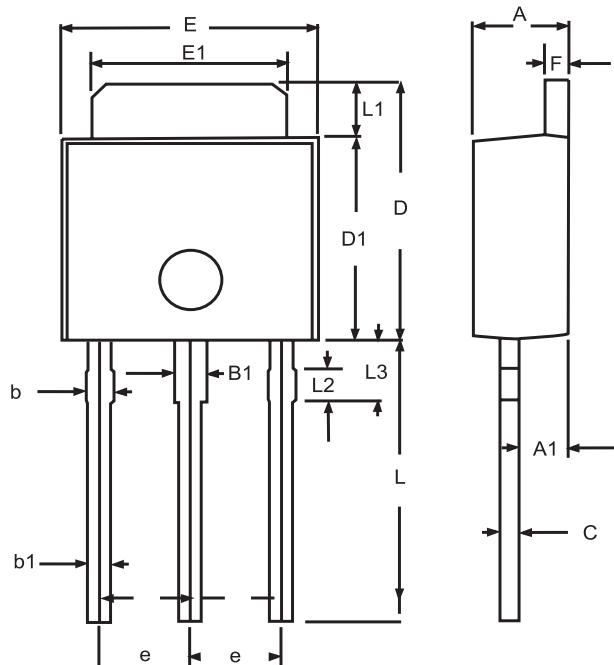


Figure 13. Normalized Thermal Transient Impedance Curve

STU/D2455PLS

PACKAGE OUTLINE DIMENSIONS

TO-251

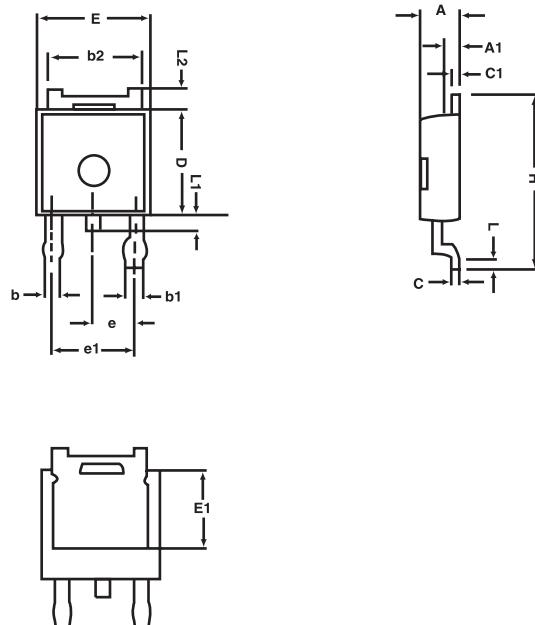


| SYMBOLS | MILLIMETERS | | INCHES | |
|---------|-------------|-------|--------|-------|
| | MIN | MAX | MIN | MAX |
| A | 2.20 | 2.40 | 0.087 | 0.095 |
| A1 | 1.100 | 1.300 | 0.043 | 0.051 |
| B1 | 0.650 | 1.050 | 0.026 | 0.041 |
| b | 0.500 | 0.900 | 0.020 | 0.035 |
| b1 | 0.400 | 0.800 | 0.016 | 0.32 |
| C | 0.400 | 0.600 | 0.016 | 0.024 |
| D | 6.700 | 7.300 | 0.264 | 0.287 |
| D1 | 5.400 | 5.650 | 0.213 | 0.222 |
| E | 6.40 | 6.650 | 0.252 | 0.262 |
| e | 2.100 | 2.500 | 0.083 | 0.098 |
| F | 0.400 | 0.600 | 0.016 | 0.024 |
| L | 7.000 | 8.000 | 0.276 | 0.315 |
| L1 | 1.300 | 1.700 | 0.051 | 0.067 |
| L2 | 0.700 | 0.900 | 0.028 | 0.035 |
| L3 | 1.400 | 1.800 | 0.055 | 0.071 |

STU/D2455PLS

PACKAGE OUTLINE DIMENSIONS

TO-252

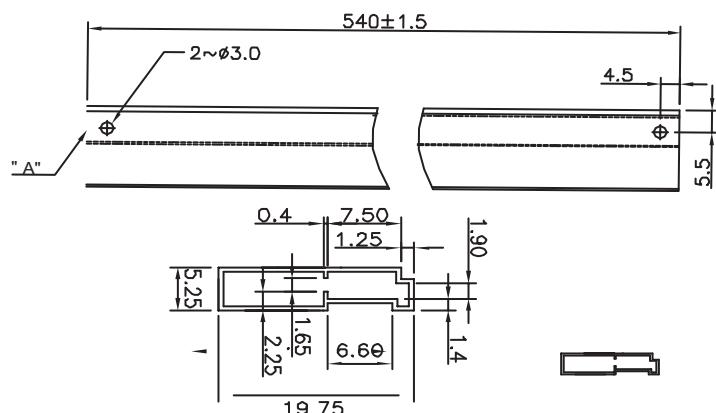


| SYMBOLS | MILLIMETERS | | INCHES | |
|---------|-------------|-------|--------|-------|
| | MIN | MAX | MIN | MAX |
| A | 2.25 | 2.35 | 0.089 | 0.093 |
| A1 | 0.95 | 1.05 | 0.037 | 0.041 |
| b | 0.77 | 0.85 | 0.030 | 0.033 |
| b1 | 0.84 | 0.94 | 0.033 | 0.037 |
| b2 | 5.30 | 5.45 | 0.209 | 0.215 |
| C | 0.49 | 0.53 | 0.019 | 0.021 |
| D | 6.00 | 6.20 | 0.236 | 0.244 |
| E | 6.40 | 6.60 | 0.252 | 0.260 |
| E1 | 3.18 | 3.67 | 0.125 | 0.145 |
| e | 2.29 | BSC | 0.090 | BSC |
| H | 9.70 | 10.10 | 0.382 | 0.398 |
| L | 1.425 | 1.625 | 0.056 | 0.064 |
| L1 | 0.650 | 0.850 | 0.026 | 0.033 |
| L2 | 0.600 | REF. | 0.024 | REF. |

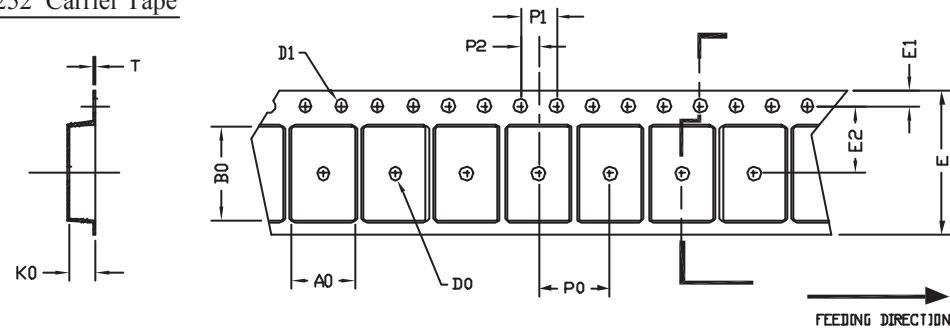
STU/D2455PLS

TO251 Tube/TO-252 Tape and Reel Data

TO-251 Tube



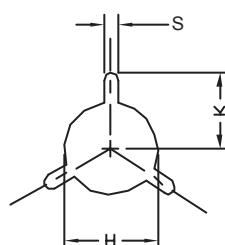
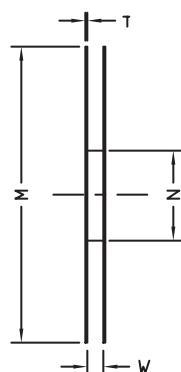
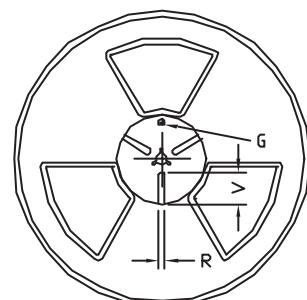
TO-252 Carrier Tape



UNIT:mm

| PACKAGE | A0 | B0 | K0 | D0 | D1 | E | E1 | E2 | P0 | P1 | P2 | T |
|-------------------|--------------|--------------|--------------|----|-----------------------|--------------|--------------|--------------|-------------|-------------|--------------|--------------|
| TO-252 (16 mm) | 6.80 ±0.1 | 10.3 ±0.1 | 2.50 ±0.1 | φ2 | φ 1.5 + 0.1 - 0 | 16.0 0.3± | 1.75 0.1± | 7.5 ±0.15 | 8.0 ±0.1 | 4.0 ±0.1 | 2.0 ±0.15 | 0.3 ±0.05 |

TO-252 Reel



UNIT:mm

| TAPE SIZE | REEL SIZE | M | N | W | T | H | K | S | G | R | V |
|-----------|-----------|----------------|---------------|----------------------|-----|--------------------------|------|--------------|-----|-----|-----|
| 16 mm | φ 330 | φ 330 ± 0.5 | φ 97 ± 1.0 | 17.0 + 1.5 - 0 | 2.2 | φ 13.0 + 0.5 - 0.2 | 10.6 | 2.0 ± 0.5 | --- | --- | --- |